Developments on Thermometric Techniques in Probing Micro- and Nano-heat

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Temperature is always of fundamental importance in various microscopic systems ranging from solid state nano-devices physics, chemical micro-reactions and biological cells. As traditional thermometers for macroscopic systems are not applicable in microscopic systems, alternative tools have to be developed to measure temperature at micro- and nano-scale. We provide here a view of the main currently available micro- and nano-thermometry tools including microscopic infrared thermometer, thermoreflectance, micro-Raman, plasmon energy expansion thermometry (PEET), Diamond thermometers, nanomaterial-based nanothermometers and two thermometric techniques based on scanning probe microscope (SPM), namely, scanning thermal microscope (SThM) and our recently-developed scanning noise microscope at terahertz (SNoiM).

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1. Introduction

As one of the seven basic physical quantities, temperature is important for understanding the principles and pictures in general physical, chemical and biological processes. Although thermocouples and thermistors constitute to be accurate, affordable and easy-to-install experimental probes, these traditional thermometers for macro-scale systems are no longer applicable for micro- and nano-sized systems (<10 mm). Development new micro- and nano-thermometers are therefore highly demanded to explore the rich nano-science in microscopic systems in which microscopic heat generation and dissipation are generally involved. For instance, in microchips containing smaller and smaller transistors with a very high integration density, Joule heating turns out to be a bottlenecking problem in limiting further improvement of device performance and energy efficiency of post-Moore nanoelectronics. In the close vicinity or so-called thermal near-field of a hot object, energy or heat can be transferred at a rate much higher than the ideal Planck black-body radiation and the heat conduction in microscopic size can differ from classical Fourier's law due to ballistic phonon transport. Besides, electrons in nano-devices are easily driven out of equilibrium with hosting lattice, so innovative nanothermometric techniques are needed to probe both counteracting (electron and phonon) sub-systems. All these phenomena related with heat in micro- and nanoscale are fascinating, and attract considerable interests from both scientific research such as fundamental understanding of thermal conductivity and practical applications like energy transport in batteries.

Here we provide a review of the main currently available methods for mapping temperature profiles in micro- and nano-scale. As the thermometric technique becomes exceptionally challenging in microscopic systems, it is worth to ask what kind of physical effects can arise from a micro- or nano-hot-spot, how they can be utilized in thermometry and how sensitively they depend on temperature. As shown in Fig. 1, an immediate effect from a microscopic hot spot is infrared (IR) emission as stated by Planck's black-body law. It is therefore straightforward to develop microscopic infrared thermometer by collecting out-coming IR emission with an optical microscope. This IR microscope works in a passive mode and at much longer wavelengths than usual visible microscope. Different from this, active method can also be applied since the reflection, Raman scattering, luminescence effects upon an external excitation are all dependent on the temperature of the micro- or nano-hot-spot which can be utilized for thermometry.

Fig. 1 Schematics of physical effects from a micro- or nano-hot-spot which can be utilized for thermometry.
target. These effects lead to various thermometry techniques such as thermoreflectance, micro-Raman, or nanomaterial-based luminescence. In addition to the optical excitation, electron beam can also be employed and temperature-dependent plasmon can be recorded by electron energy loss spectroscopy (EELS) which results in a plasmon energy expansion thermometry (PEET). Besides, scanning probe microscope (SPM) can also be applied to realize nanothermometry: one method is to functionize the tip with thermocouple or thermistor so that the tip can work as a nano-thermometer and can be scanned directly on the sample surfaces. This technique is so called scanning thermal microscope (SThM); another approach is to use the tip to scatter in the thermal near-field the super-Planckian radiation from the hot spot and we term this technique as scanning noise microscope (SNoiM) since the near-field radiation arises essentially from the fluctuating electromagnetic (EM) fields or alternatively EM noise (either thermal Johnson noise for thermal equilibrium system or shot noise for non-equilibrium system). We describe the working principles of the above thermometry techniques and discuss their pros and cons together with typical application examples.

2. Microscopic infrared thermometer

2.1 Principle of microscopic infrared thermometer

Any objects with finite temperatures can radiate electromagnetic waves and the intensity is determined by their temperature and emissivity. The infrared thermometer collects the electromagnetic waves at infrared wavelength and the temperature of sample can be extracted according to Planck's blackbody radiation law. To map the temperature distribution of a sample surface, infrared array detectors are used in the infrared microscope (Fig. 2(a)), and each pixel converts infrared radiation into a change in the resistance of individual pixel, which then can be recorded.
by computer and transformed into two-dimensional temperature distributions. Being similar to the optical microscope in visible region, this technique is a non-contact, non-destructive and convenient method with extraordinarily fast imaging capability. On the other hand, however, the spatial resolution of this optical method is inherently restricted by the optical diffraction limit, which is typically a few microns since the infrared wavelength is rather long compared to visible light. The temperature resolution is mainly determined by the detector sensitivity and hence cooled photon detectors are typically preferred when a high temperature sensitivity is aimed. The temperature resolution is described by Noise Equivalent Temperature Difference (NETD), which specifies the smallest temperature difference that can be detected. NETD can now reach the order of ~nK and is also affected by various other factors, such as the materials and structures of infrared detectors, the detection wavelength and so on. It is worthy to mention that the absolute temperature determination depends on the accuracy of the emissivity value which is often uncertain and therefore often requires new detection mechanisms such as dual-band infrared imaging.

2.2 Applications of microscopic infrared thermometer

As a fast and convenient way for temperature analysis in micro-scale, infrared thermometer and imaging has been widely applied in many areas, such as in physics, electrical engineer, medicine and biology.\textsuperscript{25,29} Regardless of materials and experimental conditions, temperature distribution generated by either thermal agitation, optical excitation or electrical stimulation can be mapped on different sample surfaces of no matter metals, semiconductors, insulator or biological specimen. Also thermal resistance or conductance can be possibly evaluated from the results obtained with microscopic infrared thermometer. We use a commercial microscopic infrared thermometer which has a spatial resolution of about ~5 microns and a temperature sensitivity of about 40 mK. The temperature sensitivity can be improved to less than 1mK with lock-in technique,\textsuperscript{57} as schematically shown in Fig. 2(a). Fig. 2(b) displays the imaging result of a carbon nanotube (CNT) fiber with a diameter of ~500nm under external bias which provides the two-dimensional temperature distribution due to Joule heating. The CNT fiber is heated after a bias applied, and there is a quadric relationship between temperature increase and external bias. The non-uniform temperature profile along the CNT arises from the energy balance between temperature increase and external bias. The high temperature sensitivity is essential to know its temperature dependence. Although the temperature dependence of reflection does exist, it appears rather weak and therefore requires additional technique such as modulation spectroscopy to achieve reasonable performance. Modulation spectroscopy started in 1960s\textsuperscript{39} and has been proved to be of great contribution to observe various samples including different micro- and nanostructures in research and some actual structures in industries like high electron mobility transistor (HEMT) and microelectromechanical systems (MEMS). Thermoreflectance thermometry, one of the modulation spectroscopy techniques, detects temperature variations of sample surface by measuring the optical reflectance correlated with temperature. Typically the sample temperature is modulated through controllable experimental condition and the changes in reflectivity is recorded with lock-in technique, as shown in Fig. 3(a).

The modulation can be done either externally through electromodulation (an electric field), thermomodulation (temperature) or piezomodulation (stress),\textsuperscript{20,25} or internally by periodically changing the wavelength or polarization condition of incident light.\textsuperscript{74} Although modulation spectroscopy measures the change of the complex dielectric function whose real and imaginary parts are correlated through Kramer–Kronig relations, the induced reflectivity change \( \Delta R \) can be approximately written as,

\[
\frac{\Delta R}{R} = \frac{\partial R}{R} \Delta T = k \Delta T
\]

where \( k \) is the thermoreflectance calibration coefficient, typically on the order of \( 10^{-2}-10^{-4} \) K\textsuperscript{1}. Due to its differential nature, modulation reflectance experiment has the potential to suppress broad background features and therefore a high sensitivity can be reached. During the measurements of electronic devices, reflectivity at a specific range of wavelength is recorded. The relative change in reflectance generated by external alternating current may modulate at an extremely small amplitude with the order around \( \sim 10^{-1}-10^{-2} \) K\textsuperscript{1}. While the investigation is achieved with the laser, so the spot size of the excitation laser directly determine the spatial resolution. The smallest spot size for 630 nm probe beam wavelength is diffraction limited giving spot diameter of about 0.5 \( \mu m \) which is better than infrared thermometry in previous section. Temperature resolution of thermoreflectance thermometry is typically better than 1 K.\textsuperscript{20}

3.2 Applications of thermoreflectance thermometry

Thermoreflectance can be applied widely in solid state electronics to provide information on heat dissipation and failure analysis in these complex devices. Fig. 3(b) and (c) display the standard and CCD-based thermoreflectance of a quantum cascade laser at the same 6 kA cm\textsuperscript{-2}/20 \( \mu m/20 \) kHz working condition.\textsuperscript{59} The CCD thermoreflectance has many potential applications, being especially well suited for small size devices, Fig. 3(d) and (e) show the thermoreflectance images (d) and temperature maps (e) of a MoS\textsubscript{2} field-effect-transistors (FETs) with large drain current at power densities from 0.6 W mm\textsuperscript{-1} to 1.8 W mm\textsuperscript{-1}.\textsuperscript{46}
These thermometric imaging results suggest that the self-heating effect may play an important role in microelectronics and optoelectronics and has to be taken into account.

4. Micro-Raman thermometry
4.1 Principle of Micro-Raman thermometry
When a material is illuminated, the excitation photons can be elastically (Rayleigh) or inelastically (Raman) scattered. Micro-Raman thermometry (Fig. 4(a) and (b)) examines the inelastic scattering processes in a crystal, in which the incident photons are scattered by phonons leading to a shift in energies of the out scattered photons with creating or annihilating an optical phonon. The probability of the inelastic scattering is temperature-dependent and is related to the occupation number of optical phonons. Measurement of the crystal lattice temperature is hence given often by the intensity ratio of the Stokes (S) and anti-Stokes (AS) lines or sometimes by their spectral shift relative to the incident excitation light. The measured temperatures can be determined by analyzing the S-to-AS intensity ratio of the corresponding phonon peak (e.g., transverse-optical (TO) in GaAs) employing the expression $\frac{I_S}{I_{AS}} \approx C \exp\left(\frac{\hbar \Omega}{kT}\right)$, where $I_S$, $I_{AS}$ are the S and AS phonon peak intensities, $\hbar \Omega$ is the phonon energy (~261 cm$^{-1}$ at room temperature for TO phonon in GaAs), and $T$ is the lattice temperature.

Fig. 3 (a) Experimental set-up for thermoreflectance mapping of laser and laser bar mirrors. Reproduced from Ref.[39]. (b) and (c) Temperature distribution maps registered by standard thermoreflectance spectroscopy (b) and CCD-thermoreflectance (c) of a quantum cascade laser at the same 6 kA cm$^{-2}$/20 μs/20 kHz working condition. 2016 IOP Publishing. Reproduced with permission from Ref. [39]. All rights reserved. Thermoreflectance images (d) and temperature maps (e) of a MoS$_2$ FETs with large drain current at power densities from 0.6 W mm$^{-1}$ to 1.8 W mm$^{-1}$. Reprinted with permission from Ref. [40]. Copyright 2017, Springer Nature.
temperature, C is a correction factor for the frequency-dependent response of the detection system. The value of C is derived from the S-to-AS intensity ratio of the phonon from a reference substrate with same material at a fixed temperature (e.g., GaAs at room temperature). With micro-Raman method, temperature resolution of ~5–10 K are given with spatial resolution depending on the excitation laser spot size and can be below 1 μm, which is similar to thermoreflectance thermometry (section 3) but is improved considerably compared to the previous passive infrared thermometry with much longer wavelength (section 2).

4.2 Applications of Micro-Raman thermometry

Micro-Raman thermometry technique is suitable to measure the in-plane temperature distribution and related thermal properties of bulk materials, thin films and nanowires. It has been used for measuring various thermoelectric materials with different dimensions, such as silicon/germanium wafers, alumina thin films, suspended graphene, bulk nanocrystalline silicon, GaAs nanowires, and Si nanowires, among others. Furthermore, some other photovoltaic measurements can be observed with this technique. When the thickness of the film is on the order of its optical absorption coefficient such that the heating can be considered independent of the depth in the film, micro-Raman thermometry allows direct determination of thermal conductivity from steady-state measurement despite of a moderated accuracy of ~20%.

Fig. 4(c) shows a Raman temperature map of a suspended film across a trench in y direction. In the center suspended part, the Raman temperature reaches as high as ~700 K, whereas the direct contact part with the supporting Ge substrate can conduct the heat efficiently to the underlying heat sink, so that the Raman temperature stays close to room temperature. Fig. 4(d) shows the same data in a more quantitative way. For different scans across the trench, the central Raman temperature varies by approximately 10%, which gives the same estimate for the accuracy of thermal conductivity.

The resolution of the above three optical thermometry (infrared, thermoreflectance and micro-Raman) is eventually limited by the diffraction and great efforts have to be spent to overcome this limit and reach super-resolution in thermometry imaging.

5. Plasmon energy expansion thermometry (PEET)

One solution to improve the spatial resolution is to utilize the electron microscope since the wavelength of high-energy electron beam is much shorter. It is however nontrivial to find a proper mechanism with applicable temperature dependence in electron microscope. Mecklenburg et al. reported an electron-microscope-based thermometry through a mechanism analogous to the optical micro-Raman technique, namely, inelastic scattering of the incident light or electron beam. This new noncontact method is called plasmon energy expansion thermometry (PEET) and can measure bulk temperature with nanoscale spatial resolution. As schematically shown in Fig. 5(a), it combines scanning transmission electron microscope (STEM) and electron energy loss spectroscopy (EELS), while it has a negligible impact on the measured sample temperature. When an electron beam created by STEM penetrates a sample, a bulk plasmon with energy can be excited.

According to the free-electron model, this energy is proportional to the square root of the valence electron density (n) of sample and can be correspondingly detected by EELS. As thermal expansion changes this electron density and thereby changes the plasmon energy, the temperature can be deduced from the plasmon energy shift measured by EELS and vice versa.

Two typical EELS spectra taken at two different temperatures are
shown in Fig. 5(b). As illustrated, when the local temperature increased from 293 K (black) to 413 K (red), the corresponding small plasmon peak shift, roughly -0.54 meV/K, is measured by the curve fitting of the peak maximum. The plasmon energy can be regarded as the energy difference between the zero loss peak and the plasmon peak. By scanning STEM electron beam over the sample and measuring the plasmon energy at each position, the plasmon energy map can be acquired. Fig. 5(c) and 5(d) show the plasmon energy maps of an aluminum wire with zero (Fig. 5(c)) and 1500 μW (Fig. 5(d)) heat power applied, respectively. In both two energy maps, the sensitive curve-fitting procedure ensure the nanoscale resolution, in which the grain boundaries and the surface details are clearly visible (as shown in Fig. 5(c) and 5(d)). Combining the two plasmon energy maps, the temperature distribution can be deduced from the peak shift at each pixel. The spectra acquisition rate was about 76 Hz for the data in Fig. 5(d). The standard deviation of the measured temperature in various small regions ranges from 20 to 30 K, which is equivalent to a temperature sensitivity of about 3K/54, 58. A variety of spectra acquisition rates yielded this same figure of merit. From this work, it is interesting to note that this PEET thermometer works more or less like Fahrenheit's mercury-in-glass thermometer and achieves its sensitivity and accuracy based on the calibrated thermal expansion.

In principle, the spatial resolution of PEET is dominated by the electron beam which has a typical dimension of 1–2 nm, therefore the spatial resolution can be much better than previous optical thermometry techniques. On the other hand, however, it is necessary to have vacuum condition and sophisticated electron microscope with EELS setup, and hence inconvenient to be applied in wider areas. In addition to electron-microscope-based thermometry, alternative approaches to reach better spatial resolution are to utilize nano-sized particles or tips as localized thermometric probes, as we discuss in next sections.

6. Diamond thermometry
6.1 The NV center and diamond thermometry

Diamond with imbedded nitrogen-vacancy (NV) centers has attracted considerable attention in many fields due to its exotic properties, including magnetic/electric-field sensing, angular-rate measurement, and bio-imaging applications. The NV center is a negatively charged point defect in diamond, consisting of a nitrogen atom and a vacancy that replaces the two adjacent carbon atoms (Fig. 6(a)). The NV center can be regarded as a two-energy-level system (Fig. 6(b)) and function as an optically addressable spin qubit with long coherence time. Since the properties of NV center are very sensitive to the local lattice thermal expansion due to temperature variation, it can work as a highly sensitive thermometer. Acosta et al. were the first to investigate the temperature dependence of magnetic-resonance spectra of NV center in the range of 280 K to 330 K by an optical method. The transition frequency between two energy levels is typically in

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**Fig. 5** (a) Schematic of the PEET instrument that based on STEM and EELS. (b) Two typical EELS spectra taken at 293 K (black) and 413 K (red), respectively. The fitted plasmon peak maxima are indicated by two arrows. (c) and (d) Plasmon energy maps of an aluminum wire with zero (c) and nonzero (d) power applied to the heater, respectively. (e) Temperature mapping deduced from (c) and (d). From [54], Reprinted with permission from AAAS.
microwave range and the accurate measurement of this temperature-dependent transition frequency is prerequisite for precise temperature measurement. For all diamond samples with different NV center concentrations (from 10 ppb ~ 15 ppm), the zero-field splitting $D$ was found to vary sensitively with a temperature coefficient of $dD/dT = -74.2(7)$ kHz/K. The large $dD/dT$ coefficient and the sharp magnetic resonance peak of the NV center make diamond with NV center a promising candidate for the high-precision thermometry at around room temperature. Later, Chen et al. and Toyli et al. investigated the temperature-dependence magnetic resonance and fluorescence spectra of NV center in two broad temperature ranges of 5.6 K to 295 K and 300 K to 700 K, respectively. Remarkably, the thermal sensitivity between room temperature and 600 K quantified by Toyli et al. was about 100 mK/Hz, and may be further increased to one order of magnitudes for NV center imbedded in the pure diamond. Kucsko et al. used a bulk diamond sample with isotopically pure carbon-12 isotope to suppress the magnetic perturbation from carbon-13 nuclear spin. Utilizing such materials and a modified spin-echo sequence method, they detected temperature variations with sensitivity up to 1.8 mK under ideal experimental conditions. Other groups have also achieved high thermal sensitivity at this similar level using analogous experimental methods and conditions. Temperature sensitivity of bulk diamond thermometry can be further improved to a thermal sensitivity of 10.1 mK/Hz by Thermal Ramsey (T-Ramsey) method.

### 6.2 Nanodiamond thermometer

As illustrated above, diamond bulk materials with NV centers can be applied as highly sensitive thermometers in a wide temperature range. However, in order to achieve a high spatial resolution of temperature detection by NV center at the nanoscale, bulk diamonds are not suitable. Plakhotnik and Gruber proved the feasibility of diamond nanothermometers for the first time and experimentally investigated the temperature-dependent photoluminescence of NV center in nanodiamonds with a size of 20–35 nm. It was found that when the temperature changed from 300 K to 670 K, the luminescence intensity of NV centers in nanodiamonds decreased to a quarter. This work supports the feasible application of diamond nanothermometers with high spatial (~10 nm) and temporal (~100 ms) resolutions in a wide temperature range.

The first practical application of nanodiamond thermometers was reported by Kucsko et al. in 2013. They used an ingenious nanowire-assisted delivery technique to induce nanodiamonds and gold nanoparticles (both~100 nm) into cells (Fig. 6(c) and (d)). When gold nanoparticles are activated by laser beams, they become the local heat sources within the cell(Fig. 6(c)). The combination of nanodiamond

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**Fig. 6 Properties of NV center.** (a) The atomic structure of a single NV center in diamond lattice. The blue, white, and black spheres represent the nitrogen, vacancy, and carbon atoms, respectively. (b) Energy level diagram with different spin states of NV center. Reprinted from Ref[62], Copyright 2014, With permission from Elsevier. (c) Schematic of NV centers within nanodiamond for monitoring temperature in living cells. Reprinted with permission from Ref. [125]. Copyright 2013, Springer Nature. (d) Confocal scan of a single cell under laser lamination. NV$_1$ and NV$_2$ represent two nanodiamond positions with different distance from the gold particle (marked by cross). Reprinted by permission from Ref. [74]. Copyright 2015, American Chemical Society.
thermometers and gold nanoparticles allows to both monitor and control the temperature at the nanoscale. These two types of nanoparticles can be imaged by a confocal microscope with a resolution of about 100 nm. Two NV\textsuperscript{1} positions (marked by NV\textsubscript{1} and NV\textsubscript{2}) at different distances from the gold nanoheater were chosen to investigate the temperature variations with the incident laser power. As illustrated in Fig. 6(d), the NV\textsubscript{1} position, which is closer to the heater than NV\textsubscript{2}, shows a stronger temperature dependence of the laser power. By increasing the laser power to 12 μW, the temperature differences of up to 3 K between NV\textsubscript{1} and NV\textsubscript{2} can be induced. This work demonstrated temperature measurement inside a single cell with sub-Kelvin sensitivity (~80 μK/Hz) and high spatial resolution (100 nm level).

6.3 Scanning Nanodiamond Microscopy
In order to obtain the spatial distribution of temperature profiles over large area, the thermometry method proposed by Kucsko et al. will not be applicable, due to the random and discrete distribution of nanodiamond thermometers. Tetienne et al.\textsuperscript{76} attached a nanodiamond thermometer (~100 nm) to the tip of an atomic force microscope (AFM), which enabled the probe to scan relative to the sample while precisely controlling the distance between the sample and the tip (Fig. 7(a),\textsuperscript{77,79}). This approach provides up to an order of magnitude gain in acquisition time while preserving a sub-100 nm spatial resolution both for the topography and temperature. Fig. 7(b) shows the fluorescence image of the gold nanoheater (~40 nm) as indicated by the bright spot. To acquire a temperature map, a full spin resonance spectrum is recorded at each pixel (as illustrated in Fig. 7(c)) of the scan at a constant incident laser power, from which the splitting parameter \(D\) can be deduced for each pixel and hence the resulting temperature map can be obtained (Fig. 7(d)).

7. Nanomaterial-based nanothermometers
In addition to the above nano-diamonds, there appear a variety of nanomaterials which can be utilized to realize nano-thermometry. One

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Fig. 7 (a) Schematic of scanning nanodiamond microscopy. (b) Fluorescence image of the 40 nm gold nanoheater. (c) Spin resonance spectra measured at three different pixels as indicated in (b) with corresponding color. (d) Temperature map deduced from the splitting parameter.\textsuperscript{76} Reprinted with permission from Ref. [77]. Copyright 2016, American Chemical Society.
example is quite similar to a normal mercurial thermometer and can be suitable for applications in a wide variety of microenvironments.\textsuperscript{99} It consists of a carbon nanotube containing liquid gallium inside (Fig.8(a)), and its height reflects the temperature. To read the temperature, this nanothermometer requires microscopic examination of the carbon nanotube and the gallium level with a scanning electron microscope.

Since the carbon nanotube technique is quite inconvenient and not applicable in wide areas, several other approaches have been attempted to detect temperature in cells via emission intensity or lifetime of organic dyes\textsuperscript{82,83} and transition-metal ions,\textsuperscript{84,85} and they all can provide a result of average temperature for a single cell. Besides, J-M Yang \textit{et al.} proposed that quantum dot is better because of its brighter exhibition, broader excitation profile for multiplexing and better photostability than organic dyes An instrumental setup is schematically shown in Fig. 8(b).\textsuperscript{86} The temperature sensitivity of quantum dots is basically immune to environment variations. Furthermore, rare-earth nanothermometers are also widely studied, especially in aqueous media or in vivo. Similar to quantum dots, rare-earth nanothermometers also use spectral methods to detect temperature. Note that there are three different biological optical transparency windows (BW; I: 750-950 nm, II: 1000-1350 nm, III: 1500-1800 nm) for near-infrared (NIR).\textsuperscript{86-88} BW-I is commonly exploited for effective NIR laser excitation,\textsuperscript{89,90} BW-II is better for NIR imaging at greater tissue depths,\textsuperscript{91-93} and BW-III offers improved imaging contrast.\textsuperscript{94,95,96} So it is better to excite nanothermometer in BW-I, while collect the signal in BW-II and BW-III.\textsuperscript{97,98} A. Skripka \textit{et al.}\textsuperscript{99} made a multilayered system of β-phase NaGdF\textsubscript{4} nanoparticles that were doped with Er\textsuperscript{3+}, Ho\textsuperscript{3+}, Yb\textsuperscript{3+} and Nd\textsuperscript{3+}(Fig. 8(d)). Nd\textsuperscript{3+} were excited by NIR light of 806 nm, and they detected NIR signal of Er\textsuperscript{3+}, Ho\textsuperscript{3+} and Nd\textsuperscript{3+}. The sensitivity can be around 1.1% C at the range of 20-50 C\textsuperscript{99} and resolution (~0.1 K) (instrument is shown in Fig. 8(c)).\textsuperscript{100} What’s more, DNA can also be applied to make nanothermometer, and it can respond linearly up to 50 °C in temperature range (Fig. 8(e)).\textsuperscript{101}

Although the nanomaterials can work as native and agile marker to measure local temperature, the imaging capability of these nanomaterial-based thermometry appears to be limited because of the uncontrollable distributions of nanomaterials. It is therefore desirable to have controllable local probes in the imaging thermometry. For this sake, scanning probe microscope (SPM) can be very much helpful as we can see in the following two sections (scanning thermal microscope and scanning noise microscope).

8. Scanning thermal microscope (SThM)

8.1 Principle

Inheriting from SPM such as scanning tunneling (STM) and atomic force microscopy (AFM), scanning thermal microscopy (SThM) appears as a promising nanoscale thermal imaging technique with excellent spatial resolution (~10 nm). Williams and Wickramasinghe\textsuperscript{102} first developed the thermocouple integrated scanning probes to obtain the topography of electrically insulating surfaces by using thermal signals as feedback. Although they were not aiming at measuring the thermal distribution, their idea facilitated the development of SThM. So far, AFM-based SThM is widely applied to different materials including metals, semiconductors and insulators. Different from standard AFM, the cantilever probe in SThM is integrated with a thermal sensor and related electronic modules record the temperature distribution of the sample surface as well as the topography when the probe is scanned. The thermal sensors are usually thermocouples, thermistors, or Schottky diodes.\textsuperscript{103,104} SThM typically has two measurement modes, the active

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**Fig. 8** Several types of nanothermometer: (a) carbon nanotube with gallium;\textsuperscript{81} Reprinted with permission from Ref. [81]. Copyright 2002, Springer Nature. (b) quantum dots nanothermometer;\textsuperscript{86} Reprinted with permission from Ref. [86]. American Chemical Society. (c) nanothermometer based on triplet-triplet annihilation mechanism;\textsuperscript{98} Reprinted with permission from Ref. [100]. Copyright 2018, Springer Nature. (d) nanoparticles doped with Er\textsuperscript{3+}, Ho\textsuperscript{3+}, Yb\textsuperscript{3+} and Nd\textsuperscript{3+} and their TEM image;\textsuperscript{98} Reprinted with permission from Ref. [98]. Copyright 2017, The Royal Society of Chemistry. (e) when temperature changes, changes in the molecular structure of the DNA cause changes in fluorescence intensity.\textsuperscript{100} Reprinted with permission from Ref. [101]. Copyright 2016, American Chemical Society.
mode is to measure the thermal conductivity of the sample, and the passive operation mode is to measure the temperature distribution on the surface of the sample. SThM measurement is often operated in contact mode although tapping mode is also possible. Quantitative measurement with SThM requires a sophisticated calibration process.

8.2 Applications of scanning thermal microscopy

Different from the IR emission spectroscopy mentioned above which is limited in far field detection and poor resolution, AFM-based SThM can be used in near-field to directly map the spatial distribution of temperature or thermal conductivity or to explore the fascinating phenomena in the thermal near-field. For example, fluctuational electrodynamics theories reveal that the super-Planck thermal transport dominated by phonon transport will occur in the extreme near field (gap size < 10 nm). SThM with a high stiffness probes (~10^4 Nm') which can enable measurements down to angstrom-sized gaps can be used to investigate the extreme near-field radiative heat transfer. Cui et al. used the method for probing the radiative heat transfer between an Au-coated tip and a heated Au substrate under ultrahigh vacuum conditions. The tip structure is shown schematically in Fig. 9(a) and an SEM image, in Fig. 9(b). The thermoelectric voltage (V_θ) from the Au-Cr thermocouple and the tunneling current across the nanogap between the sample and the tip are recorded simultaneously. The results reveal that when the gap size is reduced below about 2.5 nm, the thermal conductance increases with the decreasing gap size and is able to reach up to about 30 nWK" at the minimum distance within the experimental conditions. The spatial resolution of SThM is determined mainly by the size of the tip. Luo et al. developed a novel fabrication technique which significantly reduces the size of thermocouple to improve the spatial resolution. The temperature sensitivity is related with the materials of the thermocouple and the surroundings. In order to reduce the influence of the thermal transfer from the environment, Shi et al. utilized SiN and SiO to fabricate the cantilever and tip, respectively. Operating in ultrahigh vacuum environment is also an effective way to remove the effects of the thermal transport from surroundings. Besides, some special measurement techniques may also benefit the acquisition of high quality spatial distribution of temperature. For example, Li Shi et al. utilized SThM with a combined contact mode and lift mode operation to study the low-frequency acoustic phonon temperature in graphene, which was challenging through conventional IR emission spectroscopy tool. The results reveal that the measured acoustic phonon temperature is similar to the phonon scattering

![Fig. 9](https://example.com/fig9.png)

**Fig. 9** The schematic (a) and SEM image (b) of a typical Au-Cr thermocouples sensor probe for studying the radiative heat transfer in Angstrom-and nanometer-sized gaps. Reprinted with permission from Ref. [108]. Copyright 2018, Springer Nature. (c) Schematic of the Scanning Thermal microscopy setup with lock-in technique for studying thermolectric effect of graphene (as shown in (d)) Reprinted with permission from Ref. [118]. Copyright 2018, American Chemical Society. And (e) InAs nanowires. Reprinted with permission from Ref. [104]. Copyright 2016, Springer Nature.
temperature determined through the Raman 2D peak shift on the same sample. In 2015, F. Menges et al.\textsuperscript{120} had introduced an AC measurement method to study the thermoelectric effects of a self-heated nanowire (Fig. 9(d)) and later adopted by A. Harzheim et al.\textsuperscript{120} to study the geometrically enhanced thermoelectric effects in graphene nanoconstrictions (Fig. 9(b)). The schematic of AC scheme is shown in Fig. 9(c), using a lock-in amplifier to demodulate and record the thermoelectric signals and hence the temperature distributions. The results demodulated at fundamental harmonic frequency (f) arise from Peltier effect and those demodulated at second frequency (2f), from Joule heating, as demonstrated in the upper (Peltier) and lower (Joule) panels of Figs 9(d: graphene) and (c: InAs nanowire), respectively. In work from Pramod Reddy's group,\textsuperscript{120} they have compared the AC measurement with lock-in with conventional DC scheme for the same samples and significant improvement was found.

In work from our group, we utilized the SThm with an AC scheme to study the near-field electrodynamics in gallium arsenide two-dimensional electron gas. GaAs is a direct bandgap semiconductor with two energy valleys and the electrons can be driven to non-equilibrium state by biasing the source and drain. Both experiments and theories\textsuperscript{118,120} have proved that when electrons accumulate enough energy under high electric-fields, as a result they can transfer from (000) valley to (100) valley. By using SThm, we have successfully observed nonlocal hot spots of GaAs lattice which originates from the nonlocal energy dissipation of transporting hot electrons\textsuperscript{120} and thereby heating to the lattice through electron-phonon interaction.

9. Scanning noise microscope (SNoiM)

9.1 Principle of SNoiM

In downscaled nanoelectronic devices, electrons are driven out of equilibrium with hosting lattice, leading to remarkable hot electron effects.\textsuperscript{118,120} To map the local electron temperature of devices at nanoscale, we develop a kind of nearfield scanning optical microscope (NSOM) called scanning noise microscope(SNoiM).\textsuperscript{120} This method can collect terahertz electromagnetic fluctuations (noises) generated by hot electrons in sample with an ultrahigh sensitive detector, and super resolution is achieved by a very sharp metal tip which can scatter the fluctuating electromagnetic evanescent field on the sample surface. Therefore, SNoiM can be regarded as a near-field version of the microscopic infrared thermometer, as schematically shown in Fig. 10(a). Compared with SThm in contact mode, SNoiM has a promising spectroscopic freedom and works in a non-contact mode or tapping mode. The spectroscopic freedom is crucial to avoid the huge background from lattice environment, namely, the detector collects only a narrow band of electromagnetic waves which is away from the phonon resonances of the hosting lattice, such that the electromagnetic local density of states (EM-LDOS) from lattice is at least one order lower than that from electrons.\textsuperscript{120} As a result, the signal collected by SNoiM is dominated by hot electron contributions. The signal given by the detector should be proportional to the energy density of fluctuating electromagnetic evanescent field of hot electrons, scattered by tip. The energy density can be written as

$$u(z, \omega, T_e) = \rho(z, \omega)[\hbar \omega/\exp(\hbar \omega/k_B T_e) - 1]$$

Here, $z$ represents the distance between tip and sample surface, $\omega$ represents the angular frequency of detected photons, $T_e$ represents the temperature of electrons in the sample, $\rho(z, \omega)$ is the local density of states, $\hbar$ is the Planck constant and $k_B$ is the Boltzmann constant. Eventually electron temperature imaging can be realized given the fact that electron contribution ($T_e$) prevails in the final signal.

9.2 Applications of SNoiM

In a nano channel fabricated on GaAs semiconductor device, SNoiM provides for the first time the real space image of hot electron temperature distribution and associated non-local energy dissipation.\textsuperscript{120} As shown in Fig. 10(d) and (e), the electron hot spot reaches as high as ~2000K which is much higher than lattice and hence very far away from thermal equilibrium with lattice. So far, SNoiM is the only reported technique to map the electron temperature directly and it can be widely used in exploring the rich dynamics of nonequilibrium phenomena in a broad range of nano-materials and nano-devices.

10. Summary and outlook

In summary, temperature mapping with high spatial resolution has
Table 1
Comparison between different thermometric techniques.

<table>
<thead>
<tr>
<th>Name</th>
<th>Sample type</th>
<th>Temp range</th>
<th>Spatial resolution</th>
<th>Temp range</th>
<th>Temp range</th>
<th>Temp range</th>
<th>Temp range</th>
</tr>
</thead>
<tbody>
<tr>
<td>Microscopic infrared</td>
<td>Surface with large IR sensitivity</td>
<td>~1 mm</td>
<td>~100 mK</td>
<td>~1 mK</td>
<td>~1 mK</td>
<td>~300 K</td>
<td>~200 K</td>
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<tr>
<td>ELM</td>
<td>Samples with indiv. annealed</td>
<td>300-1000 K</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Micro-Raman</td>
<td>Samples with chemically</td>
<td>50-300 K</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Micro-Sum</td>
<td>Structures with large IR</td>
<td>~100 mK</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Nanotube</td>
<td>Non-contact</td>
<td>300-1000 K</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Diamond</td>
<td>Non-contact</td>
<td>~100 mK</td>
<td></td>
<td></td>
<td></td>
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<td></td>
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<tr>
<td>thermoreflectance</td>
<td>Non-contact</td>
<td>~100 mK</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Plasmon energy</td>
<td>Non-contact</td>
<td>~100 mK</td>
<td></td>
<td></td>
<td></td>
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<td></td>
</tr>
<tr>
<td>STM</td>
<td>Non-contact</td>
<td>~100 mK</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>SNoiM</td>
<td>Non-contact</td>
<td>~100 mK</td>
<td></td>
<td></td>
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</tr>
</tbody>
</table>

We review various thermometry techniques for micro- and nanosystems and Table 1 summarizes the main features of these techniques. Microscopic infrared thermometer is convenient but limited in spatial resolution due to diffraction limit; thermoreflectance, micro-Raman use active method with better spatial resolution because of shorter wavelength; plasmon energy expansion thermometry (PEET) achieves very high spatial resolution but requires complicated experiments; Diamond and other nanomaterial-based nanothermometers overcome the diffraction limit and realize high spatial resolution which is determined by the size of the nanomaterials; two SPM techniques, namely, scanning thermal microscope (SThM) and scanning noise microscope at terahertz (SNoiM) can also realize the super-resolution imaging capability and SNoiM is so far the only available technique to probe directly electron thermometry. With the rapid development of micro- and nano-thermometry techniques, much deeper understanding of nanoscale energy or heat transfer and associated non-equilibrium dynamics can be expected and will benefit the development of new electronic, optoelectronic and thermoelectric devices.

Conflict of interest

There are no conflicts to declare.

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References


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